

TOSHIBA GTR Module Silicon N Channel IGBT

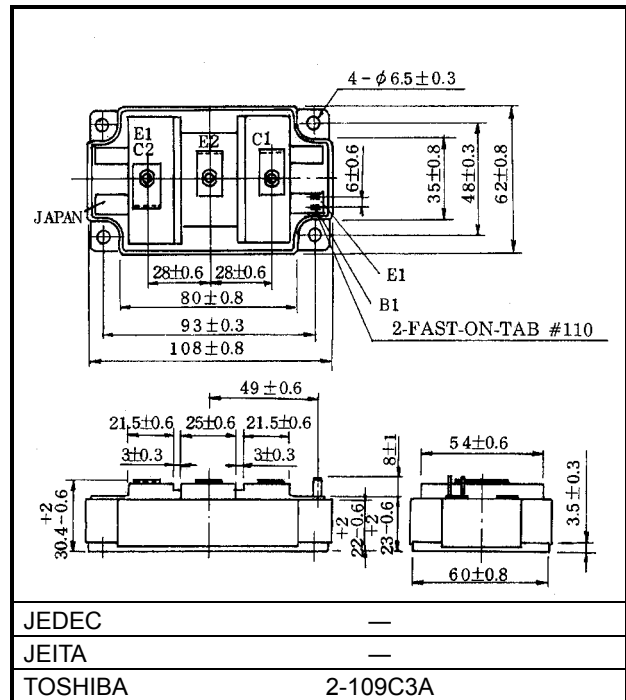
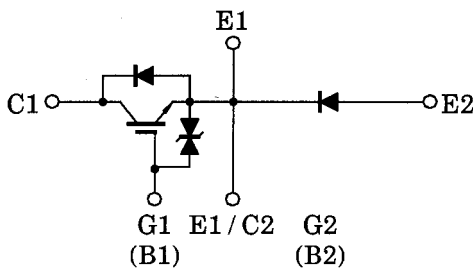
# MG200Q1JS40

High Power Switching Applications  
Chopper Applications

Unit: mm

- High input impedance
- High speed :  $t_f = 0.5\mu s$  (max)  
 $t_{rr} = 0.5\mu s$  (max)
- Low saturation voltage  
:  $V_{CE(sat)} = 4.0V$  (max)
- Enhancement-mode
- The electrodes are isolated from case.

## Equivalent Circuit



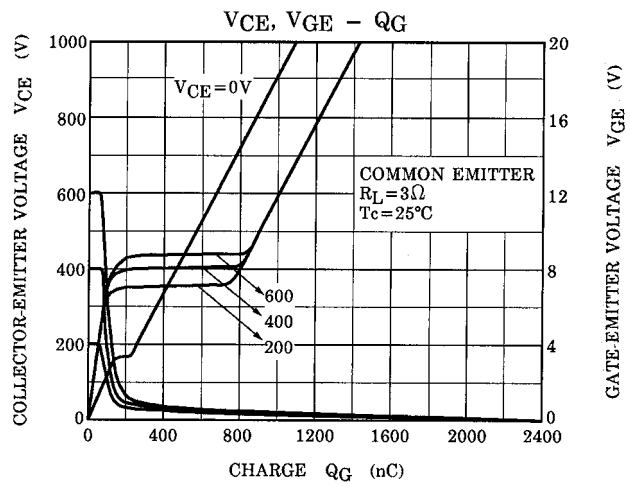
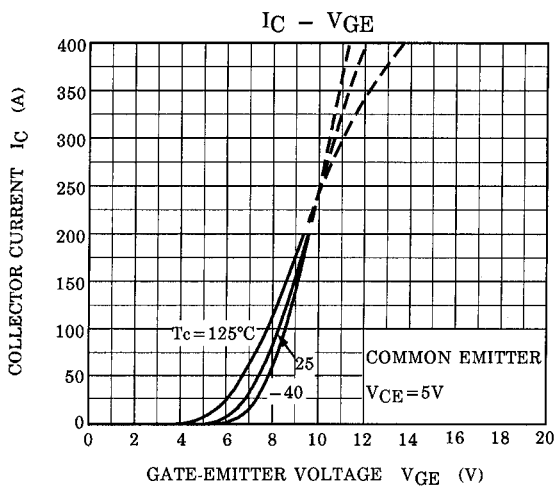
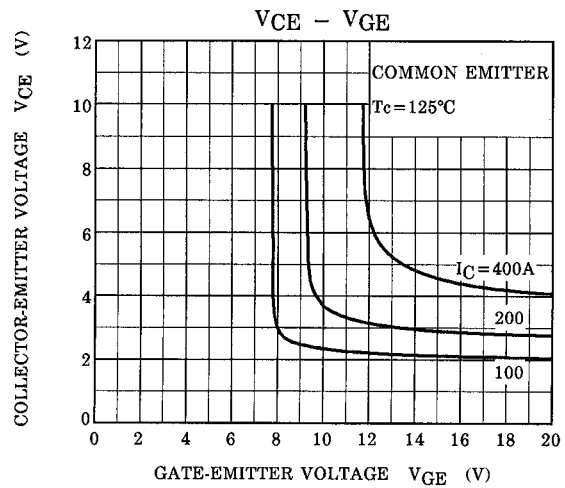
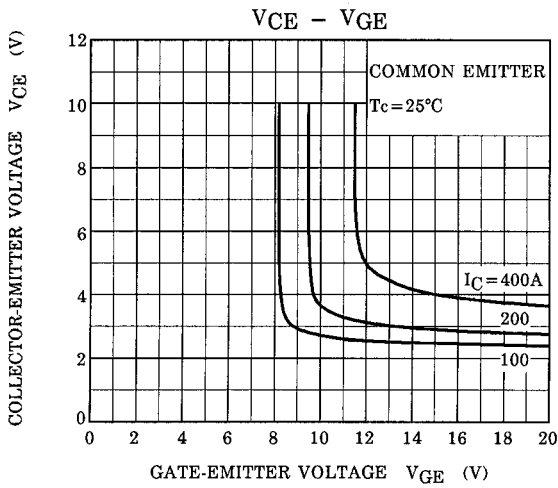
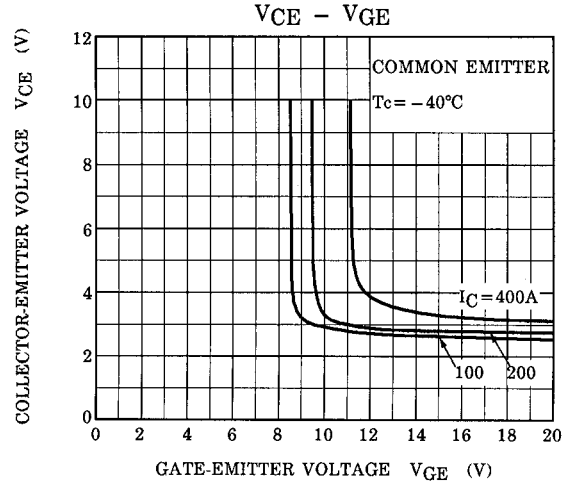
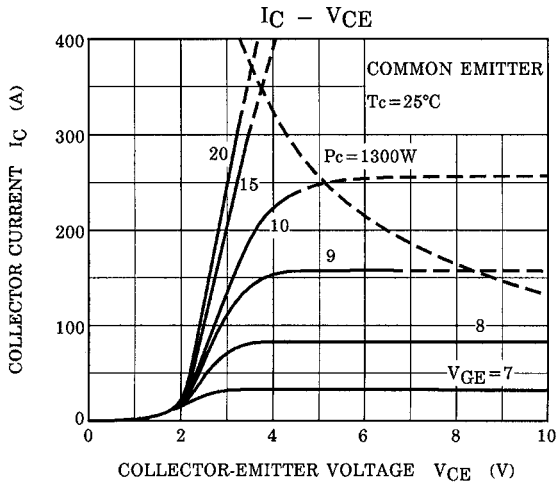
Weight: 430g

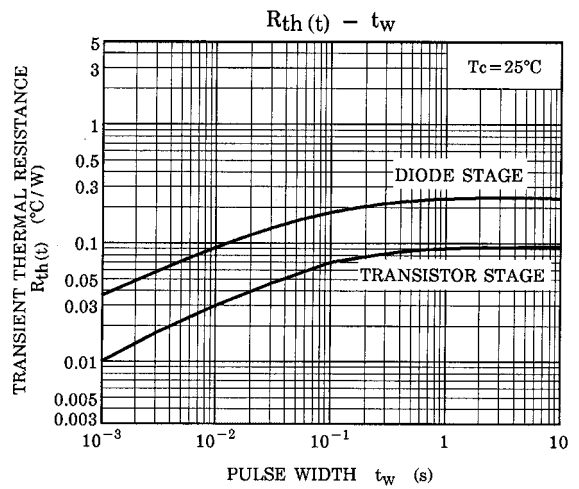
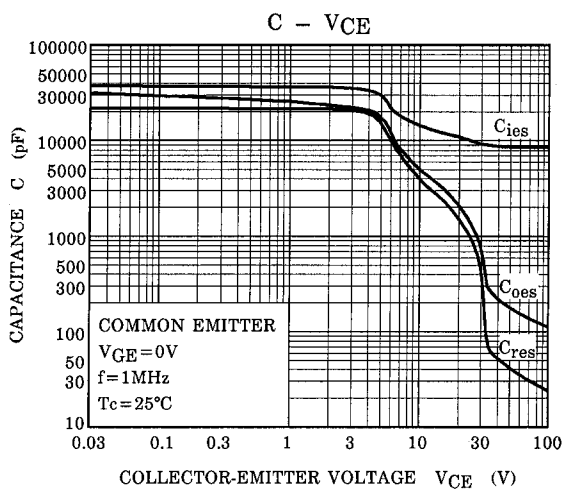
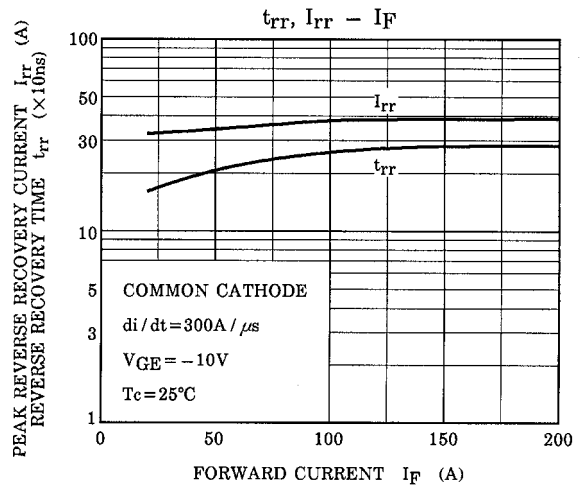
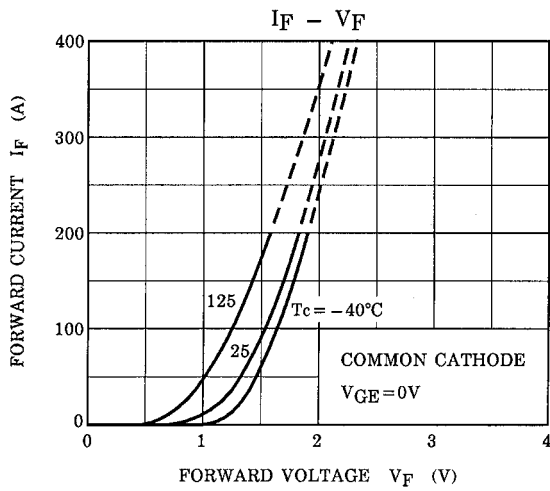
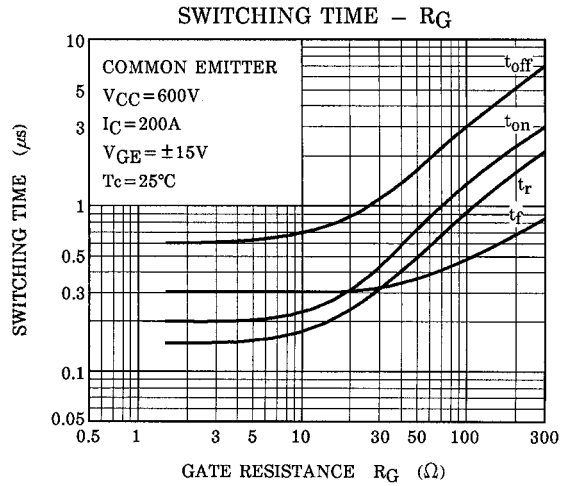
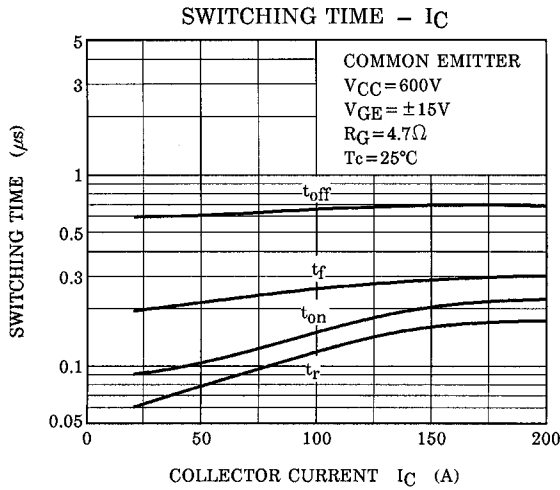
## Maximum Ratings (Ta = 25°C)

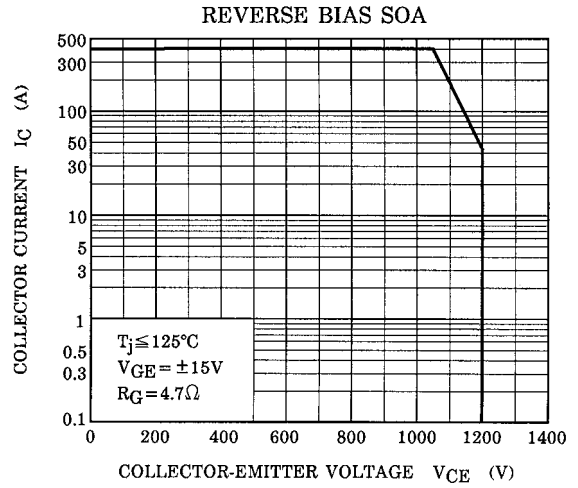
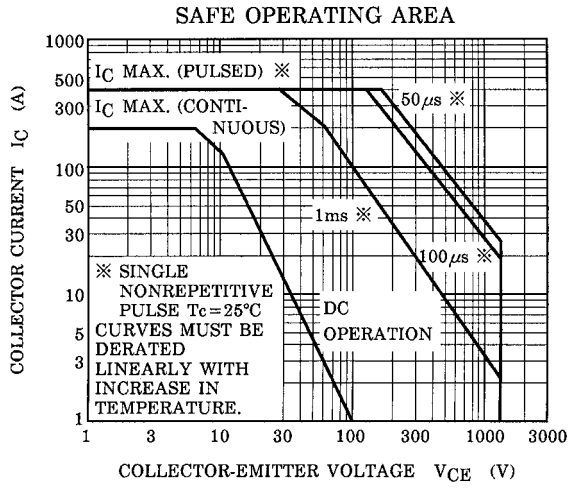
Characteristics		Symbol	Rating	Unit
Collector-emitter voltage		$V_{CES}$	1200	V
Gate-emitter voltage		$V_{GES}$	±20	V
Reverse voltage		$V_R$	1200	V
Collector current	DC	$I_C$	200	A
	1ms	$I_{CP}$	400	
Forward current	DC	$I_F$	200	A
	1ms	$I_{FM}$	400	
Collector power dissipation (Tc = 25°C)		$P_C$	1300	W
Junction temperature		$T_j$	150	°C
Storage temperature range		$T_{stg}$	-40 ~ 125	°C
Isolation voltage		$V_{isol}$	2500 (AC 1 min.)	V
Screw torque (Terminal / mounting)		—	3 / 3	N·m

## Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		$I_{GES}$	$V_{GE} = \pm 20V, V_{CE} = 0$	—	—	$\pm 20$	$\mu A$
Collector cut-off current		$I_{CES}$	$V_{CE} = 1200V, V_{GE} = 0$	—	—	2.0	mA
Gate-emitter cut-off voltage		$V_{GE(OFF)}$	$V_{CE} = 5V, I_C = 200mA$	3.0	—	6.0	V
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = 200A, V_{GE} = 15V$	—	3.0	4.0	V
Input capacitance		$C_{ies}$	$V_{CE} = 10V, V_{GE} = 0$ $f = 1MHz$	—	24000	—	pF
Switching time	Rise time	$t_r$		—	0.3	0.6	$\mu s$
	Turn-on time	$t_{on}$		—	0.4	0.8	
	Fall time	$t_f$		—	0.2	0.5	
	Turn-off time	$t_{off}$		—	0.8	1.5	
Reverse current		$I_R$	$V_R = 1200V$	—	—	2.0	mA
Forward voltage		$V_F$	$I_F = 200A, V_{GE} = 0$	—	2.0	3.0	V
Reverse recovery time		$t_{rr}$	$I_F = 200A, V_{GE} = -10V$ $di / dt = 300A / \mu s$	—	0.25	0.5	$\mu s$
Thermal resistance	Transistor	$R_{th(j-c)}$		—	—	0.096	$^{\circ}C / W$
	Diode			—	—	0.25	







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